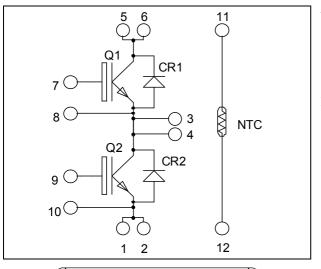
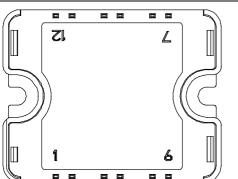


Phase leg NPT IGBT Power Module

$V_{CES} = 1200V$ $I_{C} = 15A$ @ Tc = 80°C





Pins 1/2; 3/4; 5/6 must be shorted together

Absolute maximum ratings

Symbol Max ratings Parameter Unit V_{CES} Collector - Emitter Breakdown Voltage 1200 V $T_C = 25^{\circ}C$ 25 I_{C} Continuous Collector Current $T_C = 80^{\circ}C$ 15 А Pulsed Collector Current 60 I_{CM} $T_C = 25^{\circ}C$ Gate – Emitter Voltage ±20 V V_{GE} $T_C = 25^{\circ}C$ Maximum Power Dissipation PD 140 W $T_i = 125^{\circ}C$ RBSOA Reverse Bias Safe Operating Area 30A@1150V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

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All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			250	
		$V_{CE} = 1200V$	$T_j = 125^{\circ}C$			500	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	2.5	3.2	3.7	V
		$I_{\rm C} = 15 {\rm A}$ $T_{\rm j} = 125$	$T_{j} = 125^{\circ}C$		4.0		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		4		6	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			1000		
Coes	Output Capacitance				150		pF
C _{res}	Reverse Transfer Capacitance				70		
Qg	Total gate Charge	$V_{GE} = 15V$			99		nC
Q _{ge}	Gate – Emitter Charge	$V_{Bus} = 600V$			10		
Q _{gc}	Gate – Collector Charge	$I_{\rm C}=15{\rm A}$			70		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_C = 15A$ $R_G = 33\Omega$			60		
Tr	Rise Time				50		ns
T _{d(off)}	Turn-off Delay Time				315		
T _f	Fall Time				30		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_C = 15A$ $R_G = 33\Omega$			60		ns
T _r	Rise Time				50		
T _{d(off)}	Turn-off Delay Time				356		
T _f	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125^{\circ}C$		2		T
E _{off}	Turn-off Switching Energy	$I_{C} = 15A$ $R_{G} = 33\Omega$	$T_j = 125^{\circ}C$		1		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I _{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$			100	μA
IRM			$T_{j} = 125^{\circ}C$			500	μл
I _F	DC Forward Current		$Tc = 80^{\circ}C$		15		А
	Diode Forward Voltage	$I_F = 15A$			2.8	3.3	
V _F		$I_F = 30A$			3.4		V
		$I_F = 15A$	$T_{j} = 125^{\circ}C$		2.4		
t _{rr}	Reverse Recovery Time	$I_{F} = 15A$ $V_{R} = 800V$ $di/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		240		ns
۹r			$T_j = 125^{\circ}C$		290		115
Q _{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		260		nC
Qrr			$T_{j} = 125^{\circ}C$		960		ne



Thermal and package characteristics

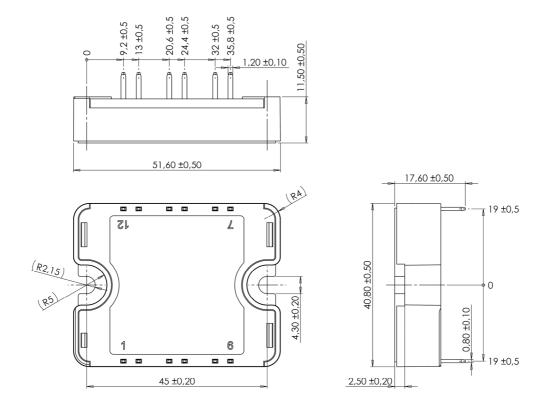
Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance		IGBT			0.9	°C/W
			Diode			2	C/ W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range		-40		150		
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature		-40		100		
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature
R_T: Thermistor value at T

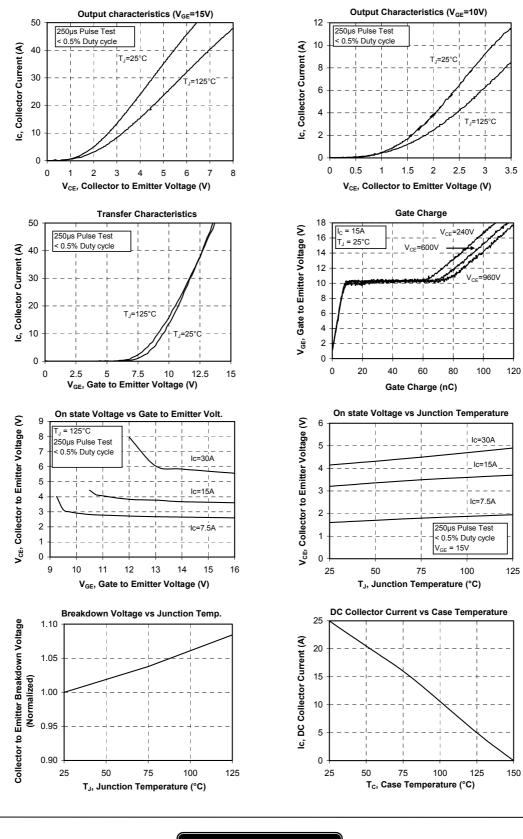
SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com



Typical Performance Curve



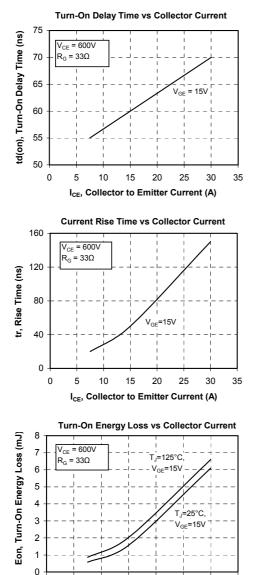
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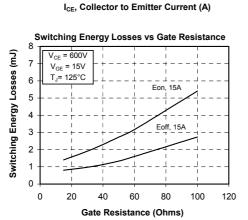
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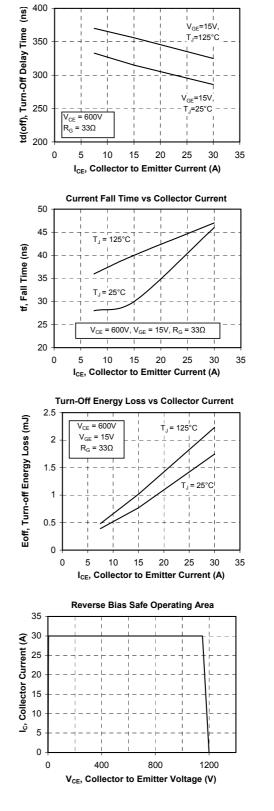
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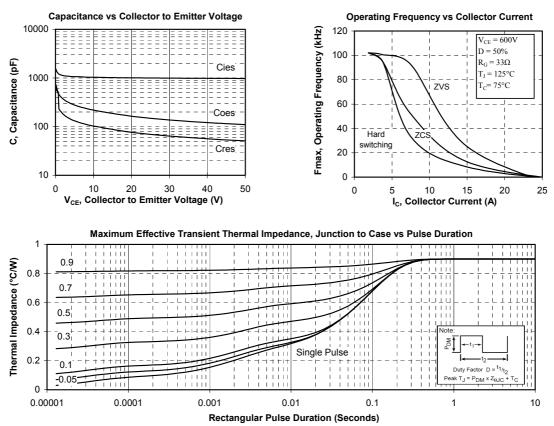
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Turn-Off Delay Time vs Collector Current



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